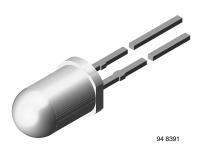


## Vishay Semiconductors

## Silicon NPN Phototransistor, RoHS Compliant



### **DESCRIPTION**

BPW96 is a silicon NPN phototransistor with high radiant sensitivity in clear, T-1¾ plastic package. It is sensitive to visible and near infrared radiation.

### **FEATURES**

Package type: leaded
Package form: T-1¾
Dimensions (in mm): Ø 5

· Leads with stand-off

High photo sensitivity

· High radiant sensitivity

· Suitable for visible and near infrared radiation

· Fast response times

• Angle of half sensitivity:  $\varphi = \pm 20^{\circ}$ 

 Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC



· Detector in electronic control and drive circuits

PRODUCT SUMMARY						
COMPONENT	I <sub>ca</sub> (mA)	φ <b>(deg)</b>	λ <sub>0.1</sub> (nm)			
BPW96B	2.5 to 7.5	± 20	450 to 1080			
BPW96C	4.5 to 15	± 20	450 to 1080			

### Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
BPW96B	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			
BPW96C	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	JE UNIT		
Collector emitter voltage		V <sub>CEO</sub>	70	V		
Emitter collector voltage		V <sub>ECO</sub>	5	V		
Collector current		I <sub>C</sub>	50	mA		
Collector peak current	$t_p/T \leq 0.5, t_p \leq 10 \text{ ms}$	I <sub>CM</sub>	100	mA		
Power dissipation	T <sub>amb</sub> ≤ 47 °C	P <sub>V</sub>	150	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C		
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C		
Soldering temperature	t ≤ 3 s	T <sub>sd</sub>	260	°C		
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	350	K/W		

### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified

# Vishay Semiconductors Silicon NPN Phototransistor, RoHS Compliant



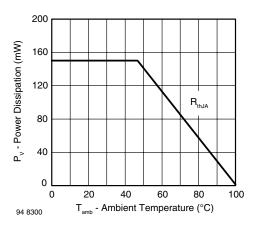


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	70			V
Collector emitter dark current	V <sub>CE</sub> = 20 V, E = 0	I <sub>CEO</sub>		1	200	nA
Collector emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}, E = 0$	C <sub>CEO</sub>		3		pF
Angle of half sensitivity		φ		± 20		deg
Wavelength of peak sensitivity		$\lambda_{p}$		850		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		450 to 1080		nm
Collector emitter saturation voltage	$E_{e} = 1 \text{ mW/cm}^{2}, \ \lambda = 950 \text{ nm}, \\ I_{C} = 0.1 \text{ mA}$	V <sub>CEsat</sub>			0.3	V
Turn-on time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>on</sub>		2.0		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>off</sub>		2.3		μs
Cut-off frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f <sub>c</sub>		180		kHz

### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified

TYPE DEDICATED CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$	BPW96B	I <sub>ca</sub>	2.5	4.5	7.5	mA
Collector light current	V <sub>CE</sub> = 5 V	BPW96C	I <sub>ca</sub>	4.5	8	15	mA



# Silicon NPN Phototransistor, RoHS Compliant Vishay Semiconductors

### **BASIC CHARACTERISTICS**

 $T_{amb}$  = 25 °C, unless otherwise specified

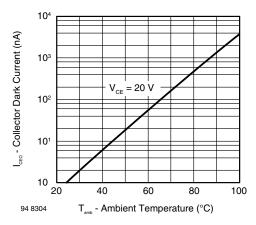


Fig. 2 - Collector Dark Current vs. Ambient Temperature

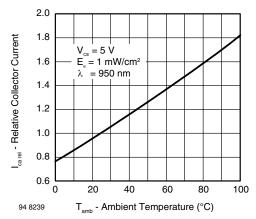


Fig. 3 - Relative Collector Current vs. Ambient Temperature

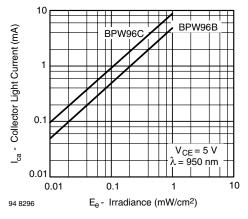


Fig. 4 - Collector Light Current vs. Irradiance

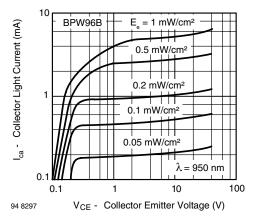


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

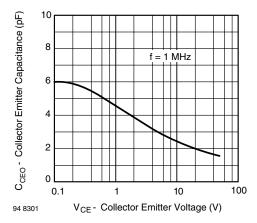


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

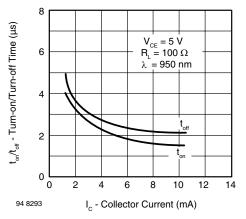


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

#### Vishay Semiconductors Silicon NPN Phototransistor, RoHS Compliant



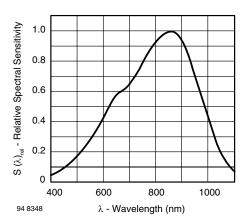


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

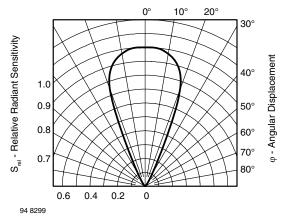
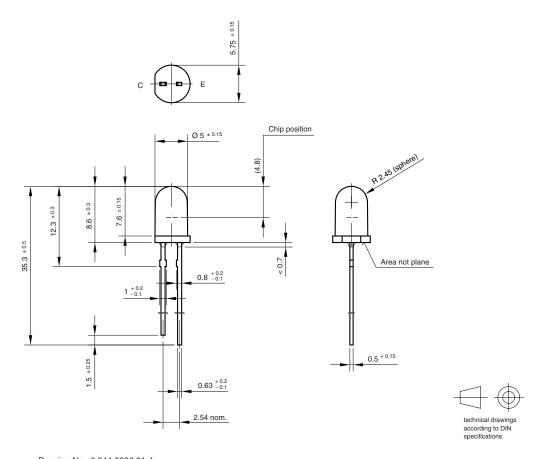


Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

### **PACKAGE DIMENSIONS** in millimeters



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